■BLOCK DIAGRAM(½)

A; • Ø Y; A; • Ø Y; A; • Ø Y; C • Ø Ø

IFUNCTION TABLE

Input		Output
Ğ	A	Y
Н	×	Z
L	Н	Н
L	L	L

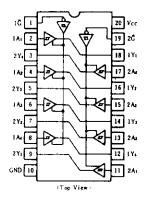
Note) H; high level,

L; low level,

X; irrelevant

Z; off (high-impedance) state of a 3-state output

PIN ARRANGEMENT



ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75 ^{\circ}\text{C}$)

	ltem	Symbol	Test Conditions		min	typ*	max	Unit	
Input voltage		Vin			2.0			v	
		VIL						0.8	v
Hysteresi	s	$V_T^* - V_T^-$	$V_{CC} = 4.75 \text{V}$			0.2	0.4		V
Output voltage		Vон Vcc=4.75V		$V_{IL} = 0.8 \text{V}, I_{OH} = -3 \text{tm A}$		2.4			
			$V_{CC} = 4.75 \text{V}, V_{IB} = 2 \text{V}$	$V_{IL}=0.5$ V, $f_{OH}=$	= - 15 mA	2.0			V
		Vol	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V},$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 24 \text{ mA}$		_		0.4		
					= 24mA	_		0.5	V
Output current		Iozн	$V_{CC} = 5.25 \text{V}, V_{IH} = 2 \text{V}, V_O = 2.7 \text{V}$		-		20	μA	
		lozt	$V_{IL}=0.8V V_O=0.4V$			_	- 20		
Input current		Īгн	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$				20	μΑ	
		1111	$V_{CC} = 5.25 \text{V}, V_{I} = 0.4 \text{V}$				-0.2	mΑ	
	I.		$V_{CC} = 5.25V, V_I = 7V$				0.1	m A	
Short-cire	cuit output current	los	$V_{CC} = 5.25 \text{V}$		40		- 225	mА	
Supply current	Output "H"						13	23	15 ms ms m. 1
	Output "L"	<i>Icc</i>	$V_{CC}=5.25V$				27	46	mА
	All outputs disabled					32	54		
Input clamp voltage V_{IK} $V_{CC} = 4.75V$, $I_{IN} =$		- 18mA				-1.5	V		

[•] V_{CC}=5V, Ta=25°C

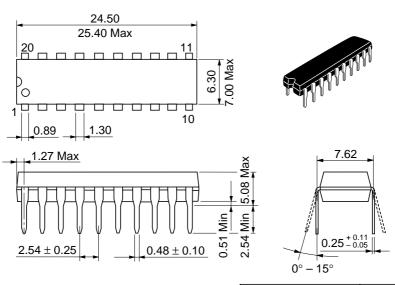
ISWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

Item Symbol		mín	typ	max	Unit			
tpl#	$C_L=45 \mathrm{pF}, R_L=667 \ \Omega$	-	12	18	ns			
t PHL		-	12	18				
tzL			20	30	πs			
t ZH			15	23	ns			
tız	$C_L = 5 \text{pF}, R_L = 667 \Omega$		15	25	ns			
tHZ			10	18	ns			
	tplH tpHL tzL tzL tzH	t_{PLH} t_{PHL} t_{ZL} t_{ZH} t_{LZ}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			

Note) Refer to Test Circuit and Waveform of the Common Item

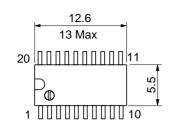
^{**} ICC is measured with all outputs open.

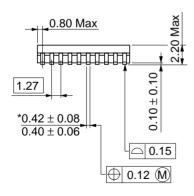
Unit: mm

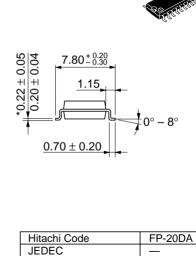


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

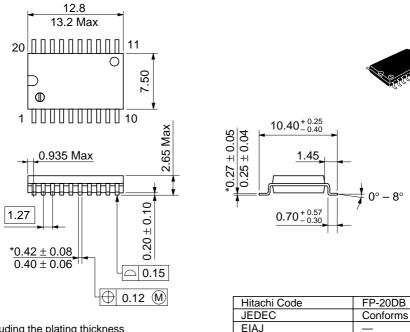
Conforms

0.31 g

EIAJ

*Dimension including the plating thickness
Base material dimension

Unit: mm



Weight (reference value)

0.52 g

*Dimension including the plating thickness
Base material dimension

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